



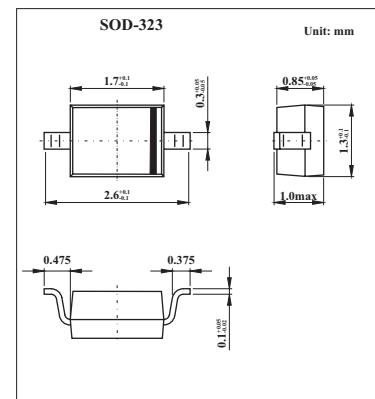
烜芯微
XUANXINWEI

1N5817WS-1N5819WS

1.0A Schottky Barrier Diode

■ Features

- For use in low voltage, high frequency inverters
- Free wheeling, and polarity protection applications.



■ Absolute Maximum Ratings Ta = 25°C

| Parameter | Symbol | 1N5817WS | 1N5818WS | 1N5819WS | Unit |
|--|-------------------|----------|------------|----------|------|
| Non-Repetitive Peak reverse voltage | V RM | 20 | 30 | 40 | V |
| Peak repetitive Peak reverse voltage | V RRM | | | | |
| Working Peak Reverse Voltage | V RWM | 20 | 30 | 40 | V |
| DC Blocking Voltage | V R | | | | |
| RMS Reverse Voltage | V R(RMS) | 14 | 21 | 28 | V |
| Average Rectified Output Current | I O | | 1 | | A |
| Peak forward surge current @=8.3ms | I FSM | | 25 | | A |
| Repetitive Peak Forward Current | I FRM | | 625 | | mA |
| Power Dissipation | P d | | 250 | | mW |
| Thermal Resistance Junction to Ambient | R _θ JA | | 500 | | K/W |
| Storage temperature | T STG | | -65 to 150 | | °C |

■ Electrical Characteristics Ta = 25°C

| Parameter | Symbol | Testconditons | Min | Typ | Max | Unit |
|---|--------|----------------------------|-----|-----|---------------|------|
| Reverse breakdown voltage 1N5817WS 1N5818WS 1N5819WS | V(BR) | IR= 1mA | 20 | | | V |
| | | | 30 | | | |
| | | | 40 | | | |
| Reverse voltage leakage current 1N5817WS 1N5818WS 1N5819WS | IR | VR=20V VR=30V VR=40V | | | 1 | mA |
| | | | | | | |
| | | | | | | |
| Forward voltage 1N5817WS 1N5818WS 1N5819WS | VF | Ir=1A Ir=3A | | | 0.45 0.75 | V |
| | | Ir=1A Ir=3A | | | 0.55 0.875 | V |
| | | Ir=1A Ir=3A | | | 0.6 0.9 | V |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| Diode capacitance | Cd | VR=4V, f=1MHz | | | 120 | pF |

■ Marking

| NO. | 1N5817WS | 1N5818WS | 1N5819WS |
|---------|----------|----------|----------|
| Marking | SJ | SK | SL |

■ Typical Characteristics

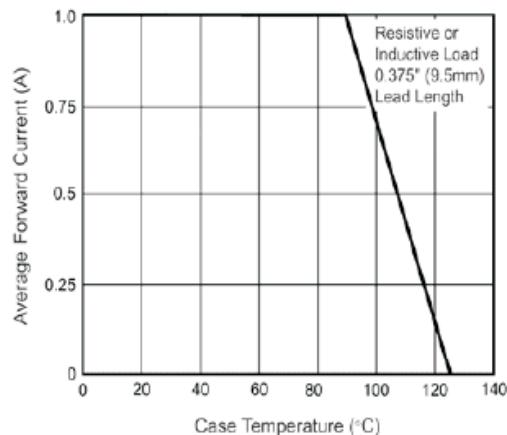


Fig.1 Forward Current Derating Curve

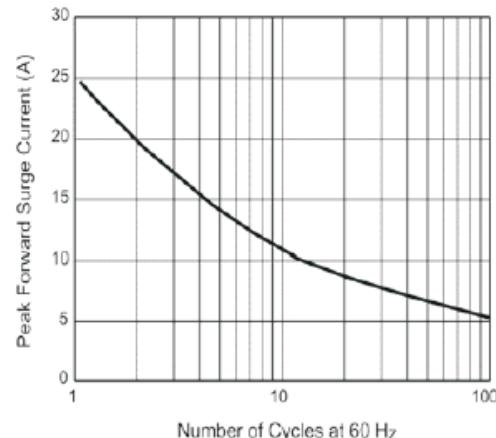


Fig.2 Maximum Non-Repetitive Peak Forward Surge Current

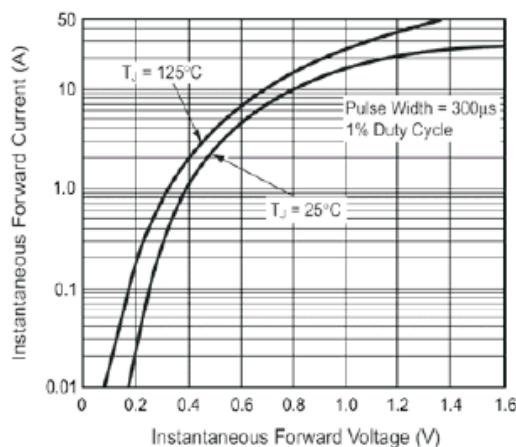


Fig.3 Typical Instantaneous Forward Characteristics

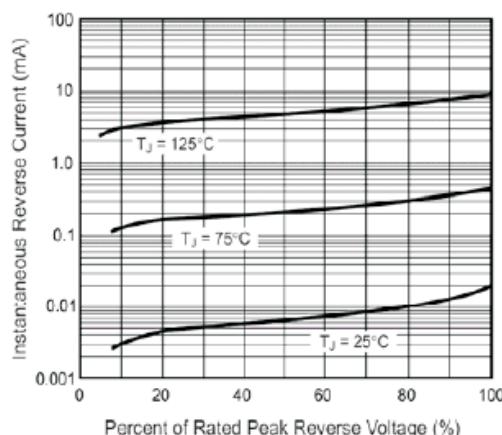


Fig.4 Typical Reverse Characteristics

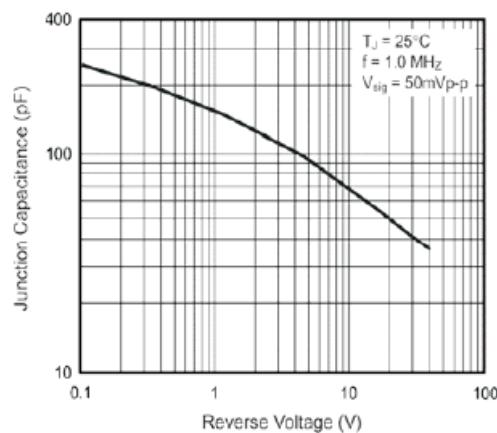


Fig.5 Typical Junction Capacitance

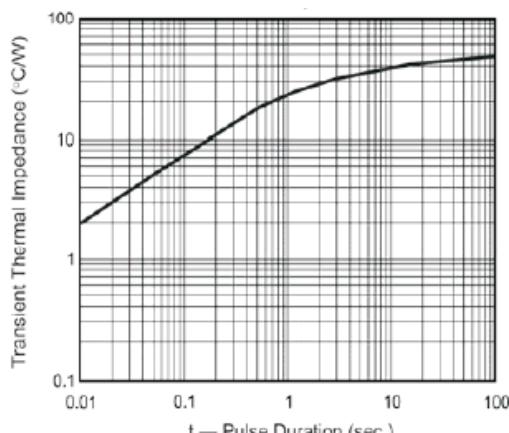


Fig.6 Typical Transient Thermal Impedance